## NSN 5961-01-553-0021

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-553-0021 **Overall Length:** 92.0 millimeters **Overall Height:** 30.0 millimeters **Overall Width:** 45.0 millimeters **End Application:** Grsl11-2k60-120-120-8050 (29019), power supply **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Product Name:** Inavy: igbts, semiconductor; cage: igbt module (n series) **Special Features:** Absolute max. Ratings at 25 deg. C: collector-emitter voltage 600v, gate-emitter voltage p/m 20 v, collector current, continuous 200 amp **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli